TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type

SSM3K123TU

Power Management Switch Applications High-Speed Switching Applications

• 1.5 V drive

• Low ON-resistance: $R_{on} = 66 \text{ m}\Omega \text{ (max) (@V_{GS} = 1.5 V)}$

 R_{on} = 43 m Ω (max) (@V_{GS} = 1.8 V) R_{on} = 32 m Ω (max) (@V_{GS} = 2.5 V) R_{on} = 28 m Ω (max) (@V_{GS} = 4.0 V)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DSS}	20	V	
Gate-Source voltage		V _{GSS}	± 10	V	
Drain current	DC	ΙD	4.2	А	
	Pulse	I _{DP}	8.4		
Drain power dissipation		P _D (Note 1)	800	mW	
		P _D (Note 2)	500		
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	−55~150	°C	

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

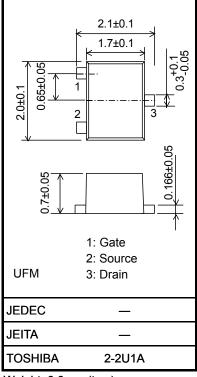
Note 1: Mounted on a ceramic board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 0.8 \text{ t, Cu Pad: } 645 \text{ mm}^2)$

Note 2: Mounted on a FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 645 \text{ mm}^2)$

Unit: mm



Weight: 6.6 mg (typ.)

Electrical Characteristics (Ta = 25°C)

Charact	eristics	Symbol	Test Condition		Min	Тур.	Max	Unit	
Drain-Source breakdown voltage	V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0V$		20	_	_	V		
Diaiii-Source breakdown voitage		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -10 \text{ V}$	12	_	_	V		
Drain cutoff curren	t	I _{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{V}$		_	_	1	μА	
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{V}$		_	_	±1	μΑ	
Gate threshold vol	tage	V _{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$		0.35	_	1.0	V	
Forward transfer a	dmittance	Yfs	$V_{DS} = 3 \text{ V}, I_D = 3.0 \text{ A}$	(Note 3)	12.5	25	_	S	
Drain-Source ON-resistance	R _{DS} (ON)	$I_D = 3.0 \text{ A}, V_{GS} = 4.0 \text{ V}$	(Note 3)	_	19	28	mΩ		
		$I_D = 3.0 \text{ A}, V_{GS} = 2.5 \text{ V}$	(Note 3)	_	23	32			
		I _D = 1.0 A, V _{GS} = 1.8 V	(Note 3)	_	28	43			
		I _D = 0.5 A, V _{GS} = 1.5 V	(Note 3)	_	35	66			
Input capacitance		C _{iss}		_	1010	_	pF		
Output capacitance		Coss	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		_	162		_	
Reverse transfer capacitance		C _{rss}			_	150		_	
Total Gate Charge	otal Gate Charge Qg					13.6	_	nC	
Gate-Source Charge		Q _{gs}	V_{DS} = 10 V, I_{DS} = 4.2 A, V_{GS} = 4 V		_	9.8	_		
Gate-Drain Charge		Q _{gd}			_	3.8	_		
Switching time	Turn-on time	t _{on}	$V_{DD} = 10 \text{ V}, I_D = 1.0 \text{ A},$		_	17	_	no	
	Turn-off time	t _{off}	$V_{GS} = 0$ to 2.5 V, $R_G = 4.7 \Omega$	2	_	30	_	ns	
Drain-Source forward voltage		V_{DSF}	$I_D = -4.2 \text{ A}, V_{GS} = 0 \text{ V}$	(Note 3)		- 0.8	- 1.2	V	

Note 3: Pulse test

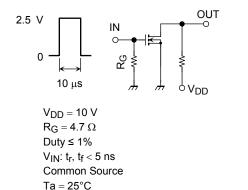
Start of commercial production 2007-04

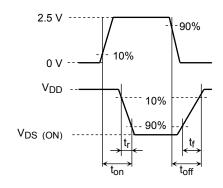
Switching Time Test Circuit

(a) Test Circuit

(b) V_{IN}

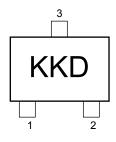
(c) Vout

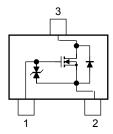




Marking

Equivalent Circuit (top view)





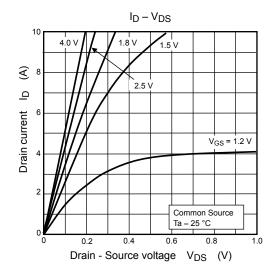
Notice on Usage

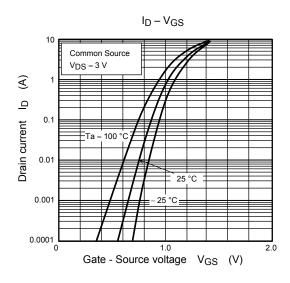
 V_{th} can be expressed as the voltage between gate and source when the low operating current value is I_D = 1 mA for this product. For normal switching operation, V_{GS} (on) requires a higher voltage than V_{th} , and V_{GS} (off) requires a lower voltage than V_{th} . (The relationship can be established as follows: V_{GS} (off) < V_{th} < V_{GS} (on).)

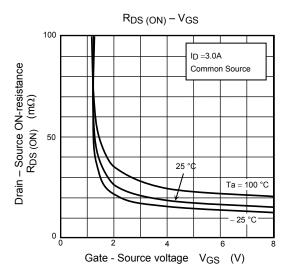
Take this into consideration when using the device.

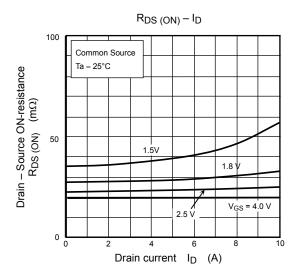
Handling Precaution

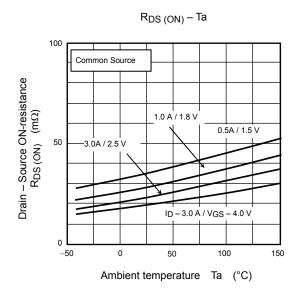
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

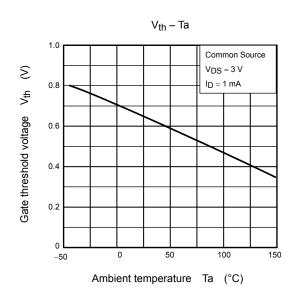


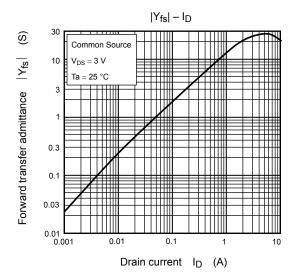


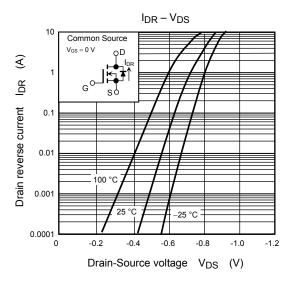


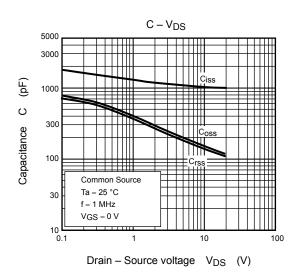


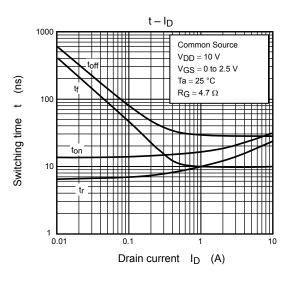


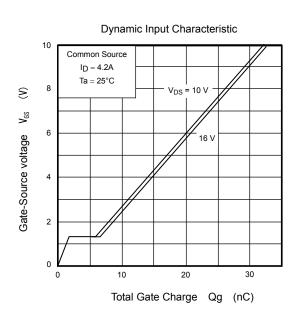




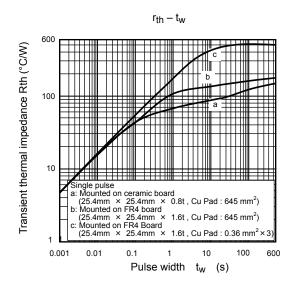


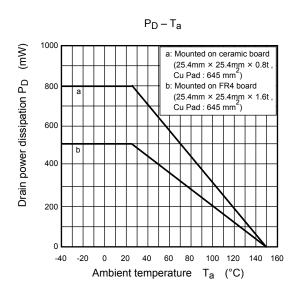






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